PAPER-II

	ELECTRON	IC	SCIENCE	4					
Si	gnature and Name of Invigilator								
1.	(Signature)	OMR Sheet No.:							
	(Name)			(To be fil	lled by	the (Candio	late)	
2.	(Signature)	R	toll No.						
	(Name)		(In figures	as pe	r adm	ission	card))
		R	oll No						
	S 8 8 1 3			(In wo	ords)				
Ti	me : 1 ¹ / ₄ hours]				[Ma	axim	um M	larks	: 100
Nι	umber of Pages in this Booklet: 8		Numb	er of Que	estion	s in t	his B	ookle	et : 50
	Instructions for the Candidates		पर	ीक्षार्थियों व	के लिए	निर्देश	 रा		
1.	Write your roll number in the space provided on the top of	1.	पहले पृष्ठ के ऊपर					र लिखि	ए ।
2.	this page. This paper consists of fifty multiple-choice type of	2.	इस प्रश्न-पत्र में पच परीक्षा प्रारम्भ होने					- नार्यामी	। गटन
۷.	questions.	3.	पाँच मिनट आपक						
3.	At the commencement of examination, the question booklet		जाँच के लिए दिये	जायेंगे, जिस	की जाँच	ग आपव	क्रो अवः	य करन	नी है :
	will be given to you. In the first 5 minutes, you are requested to open the booklet and compulsorily examine it as below:		(i) प्रश्न-पुस्तिका						
	(i) To have access to the Question Booklet, tear off		पोलिथीन बैग बिना पोलिथीन	का फाड़ल न तैस की पी	। । खुल स्टिका	गा हुइ स्वीकार	या ।बना ' न करें	स्टाकर ।	र-साल
	the paper seal / polythene bag on the booklet. Do not accept a booklet without sticker-seal / without		(ii) कवर पृष्ठ प						ष्ठ तथ
	polythene bag and do not accept an open booklet.		प्रश्नों की सं	ांख्याको अ	ाच्छी त	रह चै	कं कर	लें कि	ये पूरे
	(ii) Tally the number of pages and number of questions in the booklet with the information printed on the		हैं । दोषपूर्ण						
	cover page. Faulty booklets due to pages/questions		गये हों या उ त्रुटिपूर्ण पुरि						
	missing or duplicate or not in serial order or any		त्राटपूरा पुर लौटाकर उस						
	other discrepancy should be got replaced immediately by a correct booklet from the invigilator within the		इसके लिए उ	आपको पाँच	मिनट	दिये ज	नायेंगे [े] ।	उसके	बाद न
	period of 5 minutes. Afterwards, neither the		तो आपकी प्र			ली जार	गेगी औ	र न ही	आपक
	Question Booklet will be replaced nor any extra time will be given.		अतिरिक्त सम् (iii) इस जाँच के व			ர் கய	ग्रंग्ला र	म गण्न	गरितक
	(iii) After this verification is over, the OMR Sheet Number		पर अंकित क	गाप OMIC र दें ।	7/17/ 9/	1 37-1	राउना २	(1 N(.)	- 31//14/
4	should be entered on this Test Booklet.	4.	प्रत्येक प्रश्न के लिए	र् चार उत्तर ी	विकल्प	(A), ((B), (C) तथा ((D) दिख
4.	Each item has four alternative responses marked (A), (B), (C) and (D). You have to darken the circle as indicated below		गये हैं । आपको स			पेन से	भरकर	काला	करना है
	on the correct response against each item.		जैसा कि नीचे दिख उदाहरण : (A) (என்க ம	(C) सर्ह	उत्तर ।	है ।
	Example: (A) (B) (D) where (C) is the correct response.	5.	प्रश्नों के उत्तर केव ल		\sim				
5.	Your responses to the items are to be indicated in the OMR	٥.	अंकित करने हैं । य	गदि आप ON	AR पत्र	क पर रि	देये गये	वृत्त के	अलाव
	Sheet given inside the Paper I Booklet only. If you mark		किसी अन्य स्थान ।	पर उत्तर चिह	<u>-</u> नांकित	करते	हैं, तो उ	संका म्	ाूल्यांकन
	at any place other than in the circle in the OMR Sheet, it will not be evaluated.	6.	नहीं होगा । अन्दर दिये गये निर्	र्रेशों को ध्यान	പുര്ക്	प्रदें ।			
	Read instructions given inside carefully.	7.	कच्चा काम (Roug				अन्तिम	पृष्ट प	र करें
7. 8.	Rough Work is to be done in the end of this booklet. If you write your Name, Roll Number, Phone Number or	8.	यदि आप OMR प	ग्रंक पर निय	ात स्थान	न के अ	ालावा उ	भपना न	ाम, रोल
	put any mark on any part of the OMR Sheet, except for the		नम्बर, फोन नम्बर सके, अंकित करते						
	space allotted for the relevant entries, which may disclose your identity, or use abusive language or employ any other		अन्य अनुचित साध						
	unfair means, you will render yourself liable to		घोषित् किंये जा स						
9.	disqualification. You have to return the original OMR Sheet to the invigilators	9.	आपको परीक्षा समा लौटाना आवश्यक						
	at the end of the examination compulsorily and must not		परीक्षा भवन से बाह						
	carry it with you outside the Examination Hall. You are however, allowed to carry duplicate copy of OMR Sheet on		OMR पत्रक की डु	प्लीकेट प्रति	अपने र	साथ ले	जा सव	ह ते हैं ।	l
	conclusion of examination.		केवल नीले/काले						
	Use only Blue/Black Ball point pen. Use of any calculator or log table etc., is prohibited.	11.	किसी भी प्रकार व प्रयोग वर्जित है ।	or संगणक (कलकुर	1८ र) य	॥ लाग	८षल उ	भ॥द क
	There is no negative marks for incorrect answers.	12.	गलत उत्तरों के लिए	र कोई अंक व	काटे नह	ों जाएँग	गे ।		

ELECTRONIC SCIENCE Paper – II

Note: This paper contains **fifty** (50) objective type questions of **two** (2) marks each. All questions are compulsory.

- **1.** The p-n junction diode is a
 - (A) Passive device
 - (B) Vacuum device
 - (C) Unilateral device
 - (D) Bilateral device
- **2.** A semiconductor has temperature co-efficient of resistance
 - (A) Zero
- (B) Positive
- (C) Negative
- (D) One
- **3.** A JFET has
 - (A) One built-in diode
 - (B) Two built-in diode
 - (C) Three built-in diode
 - (D) Four built-in diode
- **4.** The superposition theorem is essentially based on the concept of
 - (A) Quality
 - (B) Linearity
 - (C) Reciprocity
 - (D) Non-linearity
- **5.** A counter that counts in binary from 0000 to 1010 is known as
 - (A) Binary counter
 - (B) Decade counter
 - (C) BCD counter
 - (D) Mod-10 counter
- **6.** A digital multiplexer is a/an
 - (A) Combinational circuit
 - (B) Sequential circuit
 - (C) Amplifier
 - (D) Memory device

- 7. An 8086 has how many number of flags?
 - (A) 5
- (B) 7
- (C) 9
- (D) 11
- **8.** In 8085, microprocessor, the register which holds the address of the next instruction to be executed is
 - (A) Instruction register
 - (B) Stack pointer
 - (C) Temporary register
 - (D) Program counter
- **9.** The Pentium III processor is a
 - (A) 16 bit processor
 - (B) 32 bit processor
 - (C) 64 bit processor
 - (D) 128 bit processor
- **10.** Demodulation is a process
 - (A) done at the transmitter
 - (B) of filtering the carrier
 - (C) of removing the sidebands
 - (D) similar to modulation
- **11.** The terms frequency pushing and pulling are related to
 - (A) Reflex Klystron
 - (B) Two cavity klystron
 - (C) Pulsed radar system
 - (D) Magnetron
- **12.** Out of the following memory types, one that is volatile is
 - (A) Magnetic disc
 - (B) Ferrite core
 - (C) Semiconductor ROM
 - (D) Semiconductor RAM

- **13.** When Q of an antenna increases, the bandwidth
 - (A) increases
 - (B) decreases
 - (C) stays constant equal to zero
 - (D) stays constant equal to unity
- **14.** The value of intrinsic-stand-off ratio of UJT should be
 - (A) > 1
- (B) <1
- (C) 0 (zero)
- (D) 10
- **15.** In a normal ECG waveform which wave has the maximum amplitude?
 - (A) P wave
- (B) R wave
- (C) Q wave
- (D) T wave
- **16.** The output impedance in an ideal Op-Amp is
 - (A) Zero
- (B) 20Ω
- (C) 60Ω
- (D) infinity
- **17.** What will be the output of the following statements ?

int a = 5, b = 2, c = 10, i = a > bVoid main ()

{print f("hello"); main ();}

- (A) 1
- (B) 2
- (C) infinite number of times
- (D) 10
- **18.** Which data communication method is used for sending data in both directions at the same time?
 - (A) Super duplex
 - (B) Simplex
 - (C) Half duplex
 - (D) Full duplex
- **19.** The highest data rate in fiber optic communication occurs in
 - (A) Single-mode fiber
 - (B) Graded-index fiber
 - (C) Multimode fiber
 - (D) Co-axial cable

20. Routh's array for a system is given below:

 S^4 1 3 5

 S^3 1 2 9

 S^2 1 5

 S^1 -3

 S^0 5

The system is

- (A) Stable
- (B) Unstable
- (C) Marginally stable
- (D) Conditionally stable

Assertion-Reason type questions:

The following items consist of two statements, one labelled as 'Assertion A' and the other labelled the 'Reason (R)'. You are to examine these two statements and decide if the Assertion (A) and the Reason (R) are individually true and if so, whether the Reason is a correct explanation of the Assertion. Select your answers to these items using the codes given below and mark your answer sheet accordingly.

Codes:

- (A) Both (A) and (R) are true and (R) is the correct explanation of (A).
- (B) Both (A) and (R) are true, but (R) is not the correct explanation of (A).
- (C) (A) is true and (R) is false.
- (D) (A) is false and (R) is true.
- **21. Assertion** (A): In a common base amplifier voltage gain is more than 1.
 - **Reason (R)**: In a common base amplifier current gain is less than 1.
- **22. Assertion (A) :** Op-Amp is used for amplification of weak signals.
 - **Reason (R)**: To rectify EMG signals, precision rectifiers are used.

- **23. Assertion** (**A**) : Gray is unweighted code.
 - **Reason (R)**: Gray code is not self complementary.
- **24. Assertion** (**A**): TDM and FDM accomplish the same end by different means.
 - **Reason (R)**: FDM involves simpler instrumentation as compared to TDM.
- **25. Assertion (A) :** A SSB system is used for broadcasting applications.
 - **Reason (R)**: The saving of power in SSB system is $\geq 75\%$.
- **26. Assertion (A) :** Dual slope A/D converter is the most preferred conversion technique employed in most of the digital multimeters.
 - Reason (R): Dual slope A/D converter provides high accuracy while at the same time suppresses the HUM effect on the input signal.
- **27. Assertion (A) :**The system of propagation in waveguides is in accordance to field theory.
 - **Reason (R)**: The system of propagation in transmission line is in accordance with circuit theory.
- **28.** Assertion (A): For a function to be odd f(-x) = -f(x).
 - **Reason (R)**: If a function is odd, its Fourier series only contains cosine terms.

- **29. Assertion** (**A**): A number of thyristors operating in parallel can not share a common heat sink.
 - **Reason (R)**: For simultaneous firing of the thyristor opto isolators may be employed in the gate driving circuit.
- **30. Assertion (A) :** ABCD parameters are transmission parameters.
 - **Reason (R)**: The relationship between input and output is given by:

$$\begin{bmatrix} V_1 \\ I_1 \end{bmatrix} = \begin{bmatrix} A & B \\ C & D \end{bmatrix} \begin{bmatrix} V_2 \\ I_2 \end{bmatrix}$$

- **31.** Consider the following devices :
 - 1. RTL
 - 2. High Speed TTL
 - 3. ECL
 - 4. CMOS

The correct sequence of their decrease in power dissipation is

- (A) 3, 1, 2, 4
- (B) 3, 1, 4, 2
- (C) 1, 3, 2, 4
- (D) 3, 2, 4, 1
- **32.** Arrange the following in terms of their increasing conductivity:
 - 1. Copper
 - 2. Steel
 - 3. Leather
 - 4. Rubber

The correct sequence is

- (A) 4, 3, 2, 1
- (B) 4, 3, 1, 2
- (C) 3, 4, 2, 1
- (D) 2, 1, 3, 4

33.	Following are the EM waves:	36.	Match the following:				
JJ.	Red colour light	30.	List – I List – II				
	 Blue colour light 		a. LED i. Heavily doped				
	3. Microwaves		b. APD ii. Coherent radiation				
	4. X-rays		c. Tunnel iii. Spontaneous				
	The correct sequence of decreasing		diode emission				
	order of wavelength is		d. Laser iv. Current gain				
	(A) 2, 4, 3, 1		The correct sequence is given by				
	(B) 1, 3, 2, 4		a b c d (A) ii i iii iv				
			(A) ii i iii iv (B) iv iii ii i				
	(C) 3, 1, 4, 2		(C) iii iv i ii				
	(D) 3, 1, 2, 4		(D) iii ii i iv				
34.	Following are the process steps to	37.	Match the following:				
	fabricate an IC:		List – I List – II				
	1. Crystal growth		a. Cassegrain i. Large B.W.				
	2. Epitaxial growth		antenna				
	3. Photo etching		b. Yagi antenna ii. Direction				
	4. Diffusion		finding				
	5. Vacuum evaporation of		c. Parabolic iii. Radar reflector antenna				
	Aluminium		d. Loop antenna iv. Directional				
	The correct sequence of fabrication is		transmission				
	(A) 1, 5, 3, 4, 2		a b c d				
	(B) 1, 2, 3, 4, 5		(A) i iv ii iii				
	(C) 1, 3, 2, 4, 5		(B) iii i iv ii (C) ii iv iii i				
	(D) 1, 2, 4, 3, 5		(C) ii iv iii i (D) iii ii iv i				
35.	Following are the modulation/	38.	Match the lists:				
	multiplexing techniques:	30.	List – I List – II				
	1. AM		(Band gap in eV) (Materials)				
	2. FM		a. 0.67 i. Ga As				
	3. CDMA		b. 1.1 ii. Cadmium sulphate				
	4. WDM		c. 1.4 iii. Si				
	The correct sequence of carrier		d. 2.4 iv. Ge				
	frequency in decreasing order is		The correct matching order is				
	(A) 1, 2, 3, 4		a b c d				
	(D) 4 2 1 2		(A) iv iii i ii				

(B)

(C)

(D)

iii

iv

ii

ii

i

iii

i

iii

i

iv

ii

iv

(B) 4, 3, 1, 2

(C)

(D)

4, 3, 2, 1

3, 4, 2, 1

39. Match the following:

	List – I		List – II
a.	Voltage	i.	increases
	series		input
	feedback		impedance
	connection		

- b. Voltage ii. decreases the shunt input feedback impedance connection
- c. Current series iii.increases the feedback output connection impedance
- d. Voltage iv. decreases the series output feedback impedance connection

The correct matching order is

	a	b	c	d
(A)	iv	ii	iii	i
(B)	iv	ii	i	iii
(C)	i	iii	iv	ii
(D)	i	ii	iii	iv

40. Match the following lists:

		List	– I		List – II
a.	Е	lectr	О-	i.	Tracing brain
	m	nyog:	ram		waves
b.	E	lectr	О-	ii.	Tracing of
	c	ardic	gram		muscular
					waves
c.	E	lectr	О-	iii.	Measurement
	eı	ncep	halogra	ım	of air in lungs
d.	S	piroı	neter	iv.	A record of
					electrical
					activity of
					heart
		a	b	c	d
(A))	i	ii	iii	iv
(B))	i	iv	iii	ii
(C))	i	iv	ii	iii
(D))	iv	iii	i	ii

41. Match the following:

	List –	I			List – I	ll
a.	Remove	es a	c	i.	Zener die	ode
	ripple					
b.	Supplie	s a	c	ii.	Filter cap	acitor
	input vo	oltage	:			
c.	Constan	ıt	dc	iii.	No	output
	output v	oltag	e		voltage	
d.	Filter	chok	e	iv.	Power	
	inducto	r			transform	ner
	a	b	C		d	
(A)	ii	iv	i		iii	
(B)	i	iv	iii	į	ii	
(C)	iv	i	ii		iii	
(D)	ii	iii	i		iv	

42. Match the following lists:

	I	List –	I		List – II	
a.	N	I axw	ells	i.	Measurement	of
	b	ridge			unknown	
					inductance	
b.	F	Iay's	bridge	ii.	Measurement	of
					high Q of coils	
c.	S	cheri	ng's	iii.	Precision	
	b	ridge			measurement	of
					capacitance	
d.	V	Veins	bridge	iv.	To measure	
					frequency	
		a	b	c	d	
(A)	i	ii	iii	iv	
(B))	iv	iii	ii	i	
(C))	iv	ii	iii	i	
(D	`	i	iii	ii	iv	

43. Match the following lists :

]	List -	– I		List – II
a.	C	amn	na rays	i.	400-700 nm
b.	V	'isibl	le light	ii.	1-10 cm
c.	R	adio	waves	iii.	$3 \times 10^{+3} \text{ m}$
d.	N	licro	waves	iv.	$4 \times 10^{-11} \text{ m}$
		a	b	c	d
(A))	i	ii	iii	iv
(B))	iv	iii	ii	i
(C))	iv	i	iii	ii
(D))	ii	iii	iv	i

44. Match the List – I and List – II :

	List - (Type counte	of	List – II (No. of flip flops required)			
a.	Mod-6	,	i. 3			
b.	Mod-1	1	ii. 4			
c.	Mod-3	31	iii. 5			
	a	b	c			
(A)) iii	ii	i			
(B)) i	ii	iii			
(\mathbf{C})) ii	iii	i			
(D)) iii	i	ii			

45. Match the following lists :

	List -	– I		List – II	
	(Uni	ts)		(Quantity)	
a.	ps/nm	/km	i.	Attenuation	
b.	dB/kn		ii.	Magnetic field	
c.	cm ² /v	- S	iii.	Dispersion	
d.	Tesla		iv.	Mobility	
	a	b	c	d	
(A) iv	i	ii	iii	
(B) iii	i	ii	iv	
(C) iii	i	iv	ii	
(D) i	iv	iii	ii	

Read the paragraph and answer the questions 46 to 50:

p-i-n photodiode contains a layer of intrinsic semi-conductor material sandwiched between p-and-n regions. The depletion layer is wholly contained within the i region. Thickness of the intrinsic region can be adjusted to produce device with optimum sensitivity and frequency response. P-i-n photodiode is most common type of depletion layer photodiode.

The other class of photodiodes, avalanche photodiodes, are reverse-biased p-n junction diodes that are operated at voltages above the breakdown voltage. Current multiplication of electron-hole pairs generated by the incident electromagnetic radiation, occurs due to avalanche process. The photomultiplication factor M_{pn} is defined as ratio of the multiplied photocurrent I_{pm} to the photocurrent I_{pho} at voltage below breakdown where no avalanche multiplication takes place.

- **46.** Semiconductors are sensitive to
 - (A) heat
 - (B) magnetic field
 - (C) light energy
 - (D) all of the above
- **47.** Which of the following elements is a semiconductor?
 - (A) Germanium
 - (B) Copper
 - (C) Carbon
 - (D) Phosphorous
- **48.** When a reverse bias is applied to a junction diode
 - (A) potential barrier is lowered
 - (B) majority carrier current is increased
 - (C) minority carrier current is increased
 - (D) potential barrier is raised
- **49.** Photo-diode is reverse biased because
 - (A) only one side is illuminated
 - (B) majority swept are reverse biased across the function
 - (C) reverse current is small as compared to photo current
 - (D) reverse current is large as compared to photocurrent
- **50.** Avalanche photodiodes are preferred over PIN diodes in optical communication systems because of
 - (A) Speed of operation
 - (B) Higher sensitivity
 - (C) Larger bandwidth
 - (D) Larger power handling capacity

Space For Rough Work